



MACMIC

June 2011

PRELIMINARY

MMF2X100J120D

1200V 100A FRED Module

RoHS Compliant

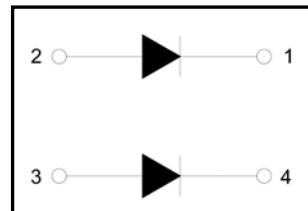
PRODUCT FEATURES

- Ultrafast Reverse Recovery Time
- Soft Reverse Recovery Characteristics
- Low Reverse Recovery Loss
- High System Power Density
- Popular SOT-227 Package



APPLICATIONS

- Inversion Welder
- Uninterruptible Power Supply (UPS)
- Plating Power Supply
- Ultrasonic Cleaner and Welder
- Converter & Chopper
- Power Factor Correction (PFC) Circuit



ABSOLUTE MAXIMUM RATINGS

 $T_C=25^\circ\text{C}$ unless otherwise specified

Symbol	Parameter	Test Conditions	Values	Unit
V_R	Maximum D.C. Reverse Voltage		1200	V
V_{RRM}	Maximum Repetitive Reverse Voltage		1200	V
$I_{F(AV)}$	Average Forward Current	$T_C=90^\circ\text{C}$, Per Diode	100	A
		$T_C=90^\circ\text{C}$, Per Moudle	200	A
		$T_C=90^\circ\text{C}$, 20KHz, Per Moudle	120	A
$I_{F(RMS)}$	RMS Forward Current	$T_C=90^\circ\text{C}$, Per Diode	141	A
I_{FSM}	Non-Repetitive Surge Forward Current	$T_J=45^\circ\text{C}$, $t=10\text{ms}$, 50Hz, Sine	1450	A
		$T_J=45^\circ\text{C}$, $t=8.3\text{ms}$, 60Hz, Sine	1600	A
I^2t	I^2t (For Fusing)	$T_J=45^\circ\text{C}$, $t=10\text{ms}$, 50Hz, Sine	10512	A^2s
		$T_J=45^\circ\text{C}$, $t=8.3\text{ms}$, 60Hz, Sine	12800	A^2s
P_D	Power Dissipation		278	W
T_J	Junction Temperature		-40 to +150	$^\circ\text{C}$
T_{STG}	Storage Temperature Range		-40 to +125	$^\circ\text{C}$
V_{isol}	Insulation Test Voltage	AC, $t=1\text{min}$	3000	V
Torque	Module-to-Sink	Recommended (M4)	0.7~1.1	N·m
Torque	Module Electrodes	Recommended (M4)	0.7~1.1	N·m
$R_{\theta JC}$	Thermal Resistance	Junction-to-Case	0.45	$^\circ\text{C}/\text{W}$
Weight			26.5	g

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ELECTRICAL CHARACTERISTICS

 $T_C = 25^\circ\text{C}$ unless otherwise specified

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{RM}	Reverse Leakage Current	$V_R=1200\text{V}$	--	--	0.5	mA
		$V_R=1200\text{V}, T_J=125^\circ\text{C}$	--	--	2	mA
V_F	Forward Voltage	$I_F=100\text{A}$	--	1.6	--	V
		$I_F=100\text{A}, T_J=125^\circ\text{C}$	--	1.38	--	V
t_{rr}	Reverse Recovery Time	$I_F=1\text{A}, V_R=30\text{V}, di_F/dt=-200\text{A}/\mu\text{s}$	--	50	--	ns
t_{rr}	Reverse Recovery Time	$V_R=600\text{V}, I_F=100\text{A}$	--	135	--	ns
I_{RRM}	Max. Reverse Recovery Current	$di_F/dt=-200\text{A}/\mu\text{s}, T_J=25^\circ\text{C}$	--	10	--	A
t_{rr}	Reverse Recovery Time	$V_R=600\text{V}, I_F=100\text{A}$	--	380	--	ns
I_{RRM}	Max. Reverse Recovery Current	$di_F/dt=-200\text{A}/\mu\text{s}, T_J=125^\circ\text{C}$	--	21	--	A

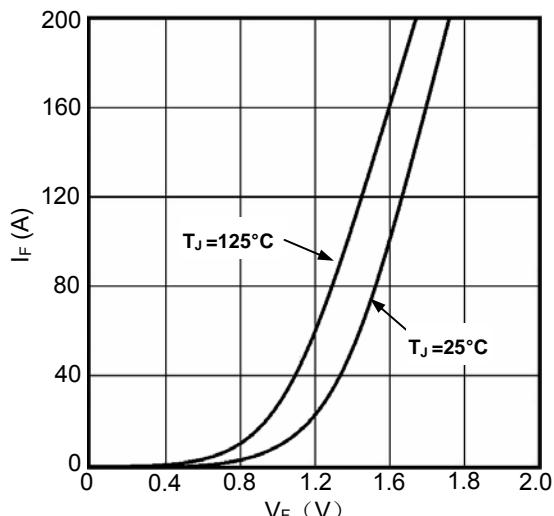
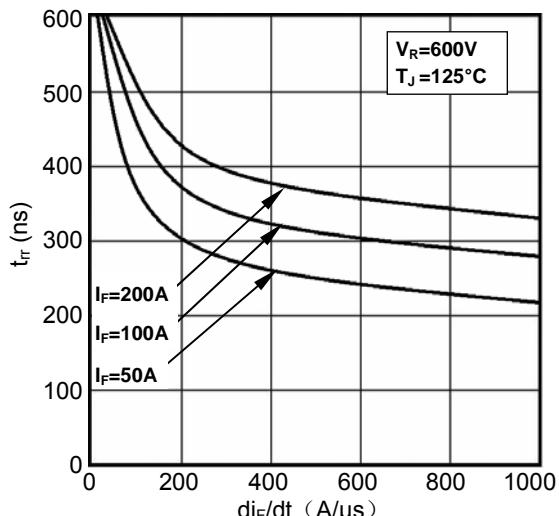
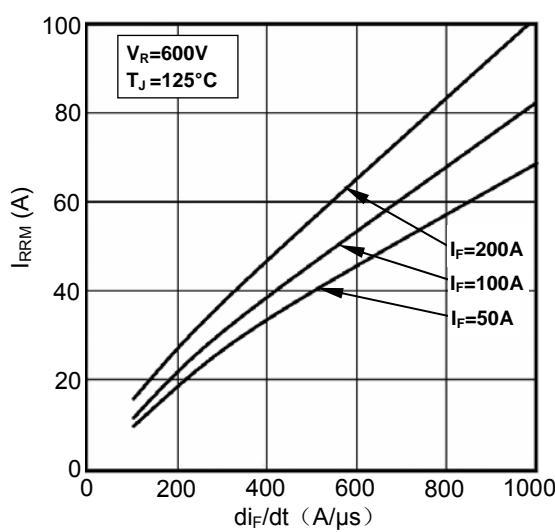
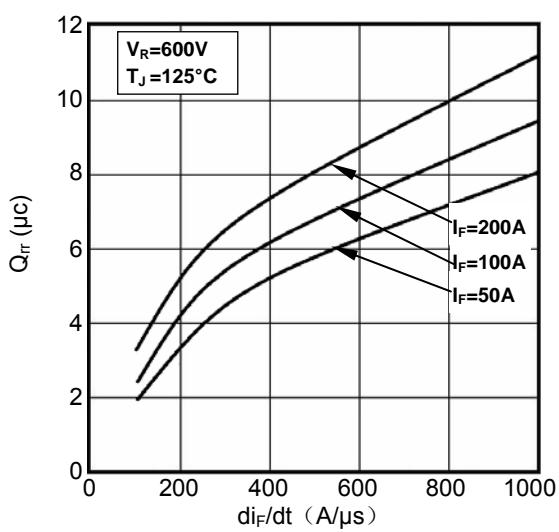


Figure 1. Forward Voltage Drop vs Forward Current

Figure 2. Reverse Recovery Time vs di_F/dt Figure 3. Reverse Recovery Current vs di_F/dt Figure 4. Reverse Recovery Charge vs di_F/dt

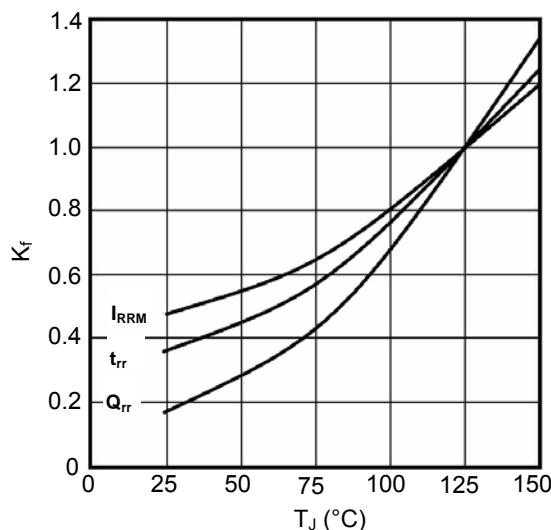


Figure 5. Dynamic Parameters vs Junction Temperature

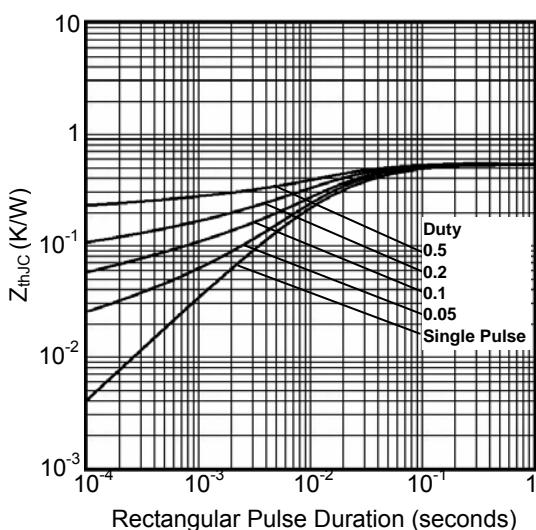
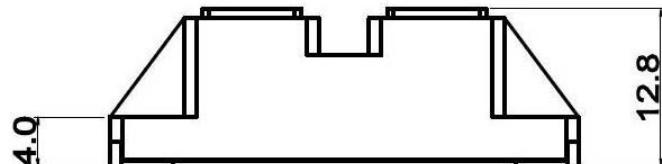
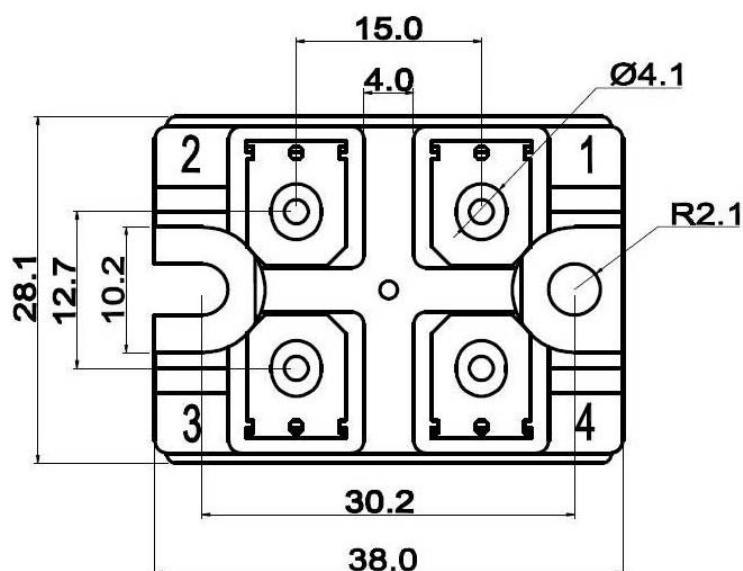


Figure 6. Transient Thermal Impedance

Dimensions (mm)
Figure 7. Package Outline